

RoHS Compliant Product  
A suffix of "-C" specifies halogen free

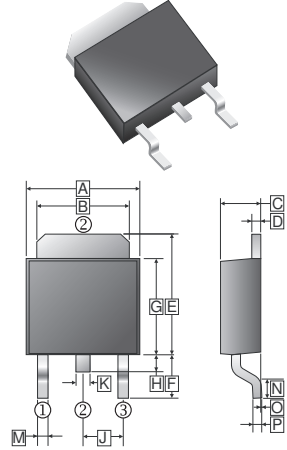
**FEATURES**

- Planar MOS Schottky technology
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

**MECHANICAL DATA**

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any

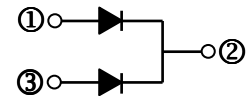
**TO-252**



| REF. | Millimeter |      | REF. | Millimeter |      |
|------|------------|------|------|------------|------|
|      | Min.       | Max. |      | Min.       | Max. |
| A    | 6.35       | 6.90 | J    | 2.30       | REF. |
| B    | 4.95       | 5.50 | K    | 0.64       | 1.14 |
| C    | 2.10       | 2.50 | M    | 0.50       | 1.14 |
| D    | 0.43       | 0.9  | N    | 1.3        | 1.8  |
| E    | 6.0        | 7.5  | O    | 0          | 0.13 |
| F    | 2.80       | REF. | P    | 0.58       | REF. |
| G    | 5.40       | 6.40 |      |            |      |
| H    | 0.60       | 1.20 |      |            |      |

**ORDER INFORMATION**

| Part Number  | Type                            |
|--------------|---------------------------------|
| SBL20A60D1   | Lead (Pb)-free                  |
| SBL20A60D1-C | Lead (Pb)-free and Halogen-free |



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, de-rate current by 20%.)

| Parameter  |              | Symbol          | Rating       | Unit        |
|--|--------------|-----------------|--------------|-------------|
| Maximum Recurrent Peak Reverse Voltage                   |              | $V_{RRM}$       | 60           | V           |
| Working Peak Reverse Voltage                             |              | $V_{RSM}$       | 60           | V           |
| Maximum DC Blocking Voltage                              |              | $V_{DC}$        | 60           | V           |
| Maximum Average Forward Rectified Current                | (Per Leg)    | $I_F$           | 10           | A           |
|  | (Per Device) |                 | 20           |             |
| Peak Forward Surge Current, 8.3 ms single half sine-wave |              | $I_{FSM}$       | 120          | A           |
| Voltage Rate of Change (Rated $V_R$ )                    |              | $dv/dt$         | 10000        | V / $\mu s$ |
| Typical Thermal Resistance <sup>3</sup>                  |              | $R_{\theta JC}$ | 6            | °C /W       |
| Operating and Storage Temperature Range                  |              | $T_J, T_{STG}$  | 150, -55~150 | °C          |

**ELECTRICAL CHARACTERISTICS**

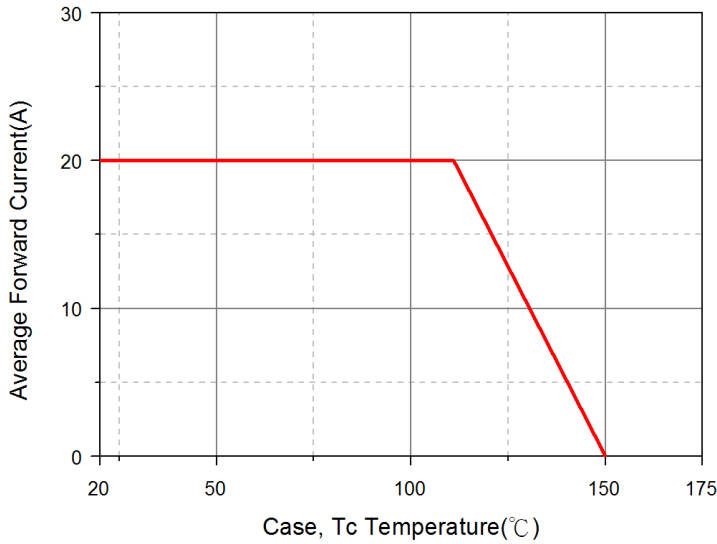
| Parameter  | Symbol | Typ. | Max. | Unit | Test Condition             |
|--|--------|------|------|------|----------------------------|
| Maximum Instantaneous Forward Voltage                                | $V_F$  | 0.49 | 0.55 | V    | $I_F=5A, T_J=25^\circ C$   |
|  |        | 0.6  | 0.65 |      | $I_F=10A, T_J=25^\circ C$  |
|  |        | 0.57 | -    |      | $I_F=10A, T_J=125^\circ C$ |
| Maximum DC Reverse Current at Rated DC Blocking Voltage <sup>2</sup> | $I_R$  | -    | 0.5  | mA   | $T_J=25^\circ C$           |
|  |        | -    | 20   |      | $T_J=100^\circ C$          |
| Typical Junction Capacitance <sup>1</sup>                            | $C_J$  | 280  | -    | pF   |                            |

Notes:

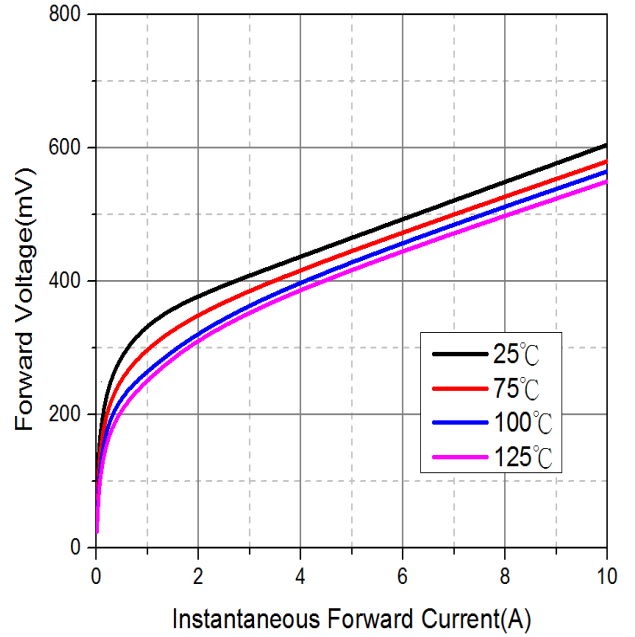
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Pulse Test : Pulse Width=300 $\mu s$ , Duty Cycle  $\leq$  2.0%.
3. Surface mounted on 2.5cm x 2.5cm x 0.5mm copper pad area.

**RATINGS AND CHARACTERISTIC CURVES**

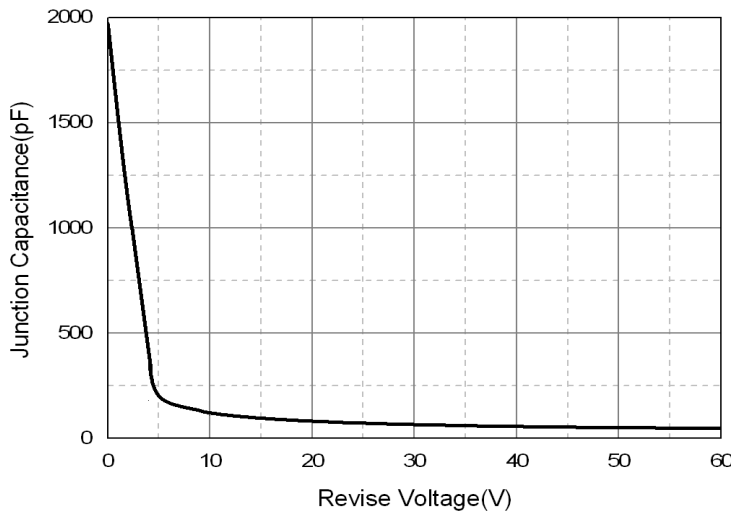
Typical Forward Current Derating Curve



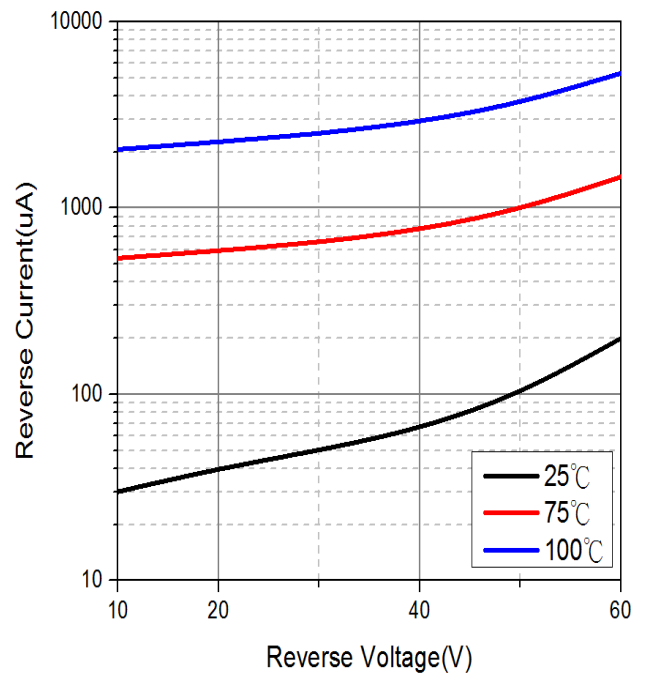
Typical Forward Characteristic



Typical Junction Capacitance



Typical Reverse Characteristic



Maximum Non-Repetitive Forward Surge Current

